X3G-OH047; X3T-OH047; X3G-OH048; X3T-OH048

Magnetic field sensor

Rev. 1 — 4 April 2011

Product specification

1. Product profile

1.1 General description

The X3G-OH047, X3G-OH048, X3T-OH047 and X3T-OH048 are sensitive magnetic field sensors, employing the magneto-resistive effect of thin film permalloy. The sensors contain two parallel supplied Wheatstone bridges at a relative angle of 45° to each other.

A rotating magnetic field in the surface parallel to the chip (x-y plane) will deliver two independent sinusoidal output signals, one following a $cos(2\alpha)$ and the other following a $sin(2\alpha)$ function, α being the angle between sensor and field direction (see Figure 5 and Figure 6).

The X3G-OH047, X3G-OH048, X3T-OH047 and X3T-OH048 are suited for high precision angle measurement applications under low field conditions (saturation field strength 25 kA/m).

The sensors can be operated at any frequency between DC and 1 MHz.

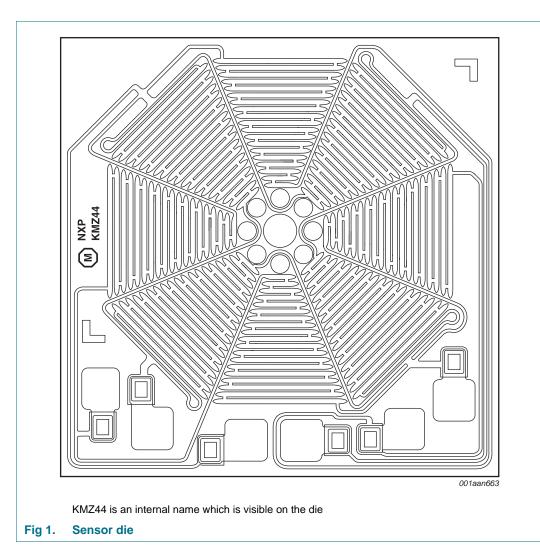
All type numbers shown in this data sheet are valid for a single-die (single sensor). The double-die has two magnetic field sensors with electrical and magnetic parameters which fulfill the specified single-die values and do not correlate to each other.

Table 1. Product overview

| Type number | Sensor | Packing |
|-------------|------------|---------------------|
| X3G-OH047 | double-die | sawn wafer; on foil |
| X3G-OH048 | single-die | sawn wafer; on foil |
| X3T-OH047 | double-die | taped on reel |
| X3T-OH048 | single-die | taped on reel |



Magnetic field sensor



1.2 Features and benefits

- Accurate and reliable angle measurement
- Mechanical robustness, contactless principle
- Wear-free operation
- Accuracy independent of mechanical tolerances
- Extended temperature range

1.3 Applications

- Steering angle and torsion
- Headlight adjustment
- Motor positioning

- Window wipers
- Fuel level
- Mirror positioning

1.4 Quick reference data

Table 2. Quick reference data

 $T_{amb} = 25 \text{ °C}; H_{ext} = 25 \text{ kA/m}; V_{CC} = 5 \text{ V}; unless otherwise specified.}$

| anno | 0,11 | | • | | | | |
|-------------------------|--|--|---------------|-----|-----|-----|----------|
| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
| V _{CC} | supply voltage | | | - | 5 | 9 | V |
| V _M | peak voltage | see Figure 3 | [1][2] | 60 | 67 | 75 | mV |
| V _{offset} | offset voltage | per supply voltage; see <u>Figure 3</u> | <u>[1]</u> | -2 | - | +2 | mV/V |
| TC _{V(offset)} | offset voltage temperature coefficient | per supply voltage; $T_{amb} = -40 \text{ °C to } +150 \text{ °C};$ see Figure 3 | <u>[1][3]</u> | -2 | - | +2 | (μV/V)/K |
| R _{bridge} | bridge resistance | | <u>[1][4]</u> | 2.7 | 3.2 | 3.7 | kΩ |
| | | | | | | | |

[1] Applicable for bridge 1 and bridge 2.

[2] $V_M = |V_{O(max)} - V_{offset}|$. Periodicity of V_M : sin(2 α) and cos(2 α), respectively.

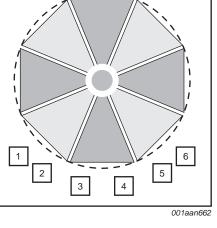
$$[3] \quad TC_{V(offset)} = \frac{V_{offset}(at \ 150 \ ^{\circ}C) - V_{offset}(at \ -40 \ ^{\circ}C)}{150 \ ^{\circ}C - (-40 \ ^{\circ}C)}$$

[4] Bridge resistance between pad 5 to pad 1 and pad 4 to pad 2.

Pinning information 2.

Table 3. Pinning

| | | 5 | |
|-----|-----------------|------------------------------|--------------------|
| Pad | Symbol | Description | Simplified outline |
| 1 | ON1 | output voltage bridge 1 | |
| 2 | ON2 | output voltage bridge 2 | |
| 3 | GND | common ground | |
| 4 | OP2 | output voltage bridge 2 | |
| 5 | OP1 | output voltage bridge 1 | |
| 6 | V _{CC} | common bridge supply voltage | |

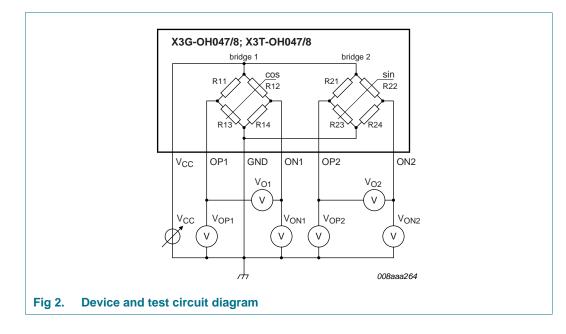


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3. Ordering information

| Table 4. Ordering information | | | | | | | |
|---------------------------------------|----------|---------------------------------|--------------|--|--|--|--|
| Type number | Package | Package | | | | | |
| | Name | Description | Version | | | | |
| X3G-OH047 | bare die | double-die; sawn wafer; on foil | OL-X3G-OH047 | | | | |
| X3G-OH048 | bare die | single-die; sawn wafer; on foil | OL-X3G-OH048 | | | | |
| X3T-OH047 | bare die | double-die; taped on reel | OL-X3T-OH047 | | | | |
| X3T-OH048 | bare die | single-die; taped on reel | OL-X3T-OH048 | | | | |

4. Circuit diagram



5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| | | ••• | , | | |
|------------------|----------------------------------|------------|---------------|------|------|
| Symbol | Parameter | Conditions | Min | Max | Unit |
| V _{CC} | supply voltage | | - | 9 | V |
| H _{ext} | external magnetic field strength | | <u>[1]</u> 25 | - | kA/m |
| T _{amb} | ambient temperature | | -40 | +150 | °C |

[1] Minimum stimulating magnetic field parallel to the chip surface (x-y plane) to achieve specified angular accuracy.

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6. Characteristics

Table 6. Characteristics

 $T_{amb} = 25 \text{ °C}; H_{ext} = 25 \text{ kA/m}^{[1]}; V_{CC} = 5 \text{ V}; unless otherwise specified.}$

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|-------------------------|---|---|---------------|-------|-------|-------|----------|
| V _{CC} | supply voltage | | | - | 5 | 9 | V |
| V _M | peak voltage | see Figure 3 | [2][3] | 60 | 67 | 75 | mV |
| TC _{VM} | peak voltage temperature coefficient | $T_{amb} = -40 \ ^{\circ}C$ to +150 $^{\circ}C$ | <u>[2][4]</u> | -0.30 | -0.36 | -0.42 | %/K |
| R _{bridge} | bridge resistance | | [2][5] | 2.7 | 3.2 | 3.7 | kΩ |
| TC _{R(bridge)} | bridge resistance temperature coefficient | $T_{amb} = -40 \text{ °C to } +150 \text{ °C}$ | [2][6] | 0.24 | 0.27 | 0.29 | %/K |
| V _{offset} | offset voltage | per supply voltage; see <u>Figure 3</u> | <u>[2]</u> | -2 | - | +2 | mV/V |
| TC _{V(offset)} | offset voltage temperature coefficient | per supply voltage; T _{amb} = -40 °C to +150 °C; see <u>Figure 3</u> | [2][7] | -2 | - | +2 | (μV/V)/K |
| V _{o(hys)} | hysteresis output voltage | see Figure 4 | [2][8] | 0 | 0.05 | 0.18 | %FS |
| ω | angular velocity | | | 0 | - | 1 | MHz |
| k | amplitude synchronism | | <u>[9]</u> | 98.9 | 100 | 101.1 | % |
| TC _k | amplitude synchronism temperature coefficient | T_{amb} = -40 °C to +150 °C | <u>[10]</u> | -0.01 | 0 | +0.01 | %/K |
| Δα | angular inaccuracy | | [11] | 0 | 0.05 | 0.1 | deg |

[1] Minimum stimulating magnetic field parallel to the chip surface (x-y plane) to achieve angular inaccuracy.

[2] Applicable for bridge 1 and bridge 2.

 $[3] \quad V_{M} = |V_{O(max)} - V_{offset}|. \mbox{ Periodicity of } V_{M}: sin(2\alpha) \mbox{ and } cos(2\alpha), \mbox{ respectively}.$

[4]
$$TC_{VM} = \frac{V_M(at\ 150\ ^\circ C) - V_M(at\ -40\ ^\circ C)}{V_M(at\ 25\ ^\circ C) \times (150\ ^\circ C - (-40\ ^\circ C))}$$

[5] Bridge resistance between pad 5 to pad 1 and pad 4 to pad 2.

$$[6] \quad TC_{R(bridge)} = \frac{R_{bridge}(at\ 150\ ^{\circ}C) - R_{bridge}(at\ -40\ ^{\circ}C)}{R_{bridge}(at\ 25\ ^{\circ}C) \times (150\ ^{\circ}C - (-40\ ^{\circ}C))}$$

[7]
$$TC_{V(offset)} = \frac{V_{offset}(at \ 150 \ ^{\circ}C) - V_{offset}(at \ -40 \ ^{\circ}C)}{150 \ ^{\circ}C - (-40 \ ^{\circ}C)}$$

$$[8] \quad V_{o(hys)I} = \left| \frac{V_{OI}(67.5^{\circ})135^{\circ} \to 45^{\circ} - V_{OI}(67.5^{\circ})45^{\circ} \to 135^{\circ}}{2 \times V_{MI}} \right|$$
$$V_{o(hys)2} = \left| \frac{V_{O2}(22.5^{\circ})90^{\circ} \to 0^{\circ} - V_{O2}(22.5^{\circ})0^{\circ} \to 90^{\circ}}{2 \times V_{M2}} \right|$$

$$[9] \quad k = \frac{V_{M1}}{V_{M2}}$$

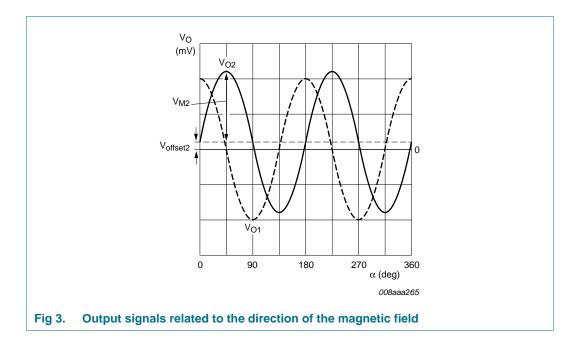
[10]
$$TC_k = \frac{k(at \ 150 \ ^\circ C) - k(at \ -40 \ ^\circ C)}{k(at \ 25 \ ^\circ C) \times (150 \ ^\circ C - (-40 \ ^\circ C))}$$

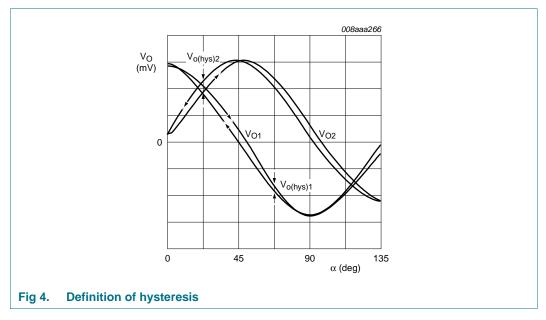
[11] $\Delta \alpha = |\alpha_{real} - \alpha_{meas}|$; V_{offset} = 0 V; inaccuracy of angular measurement due to deviations from ideal sinusoidal characteristics, calculated from the third and fifth harmonics of the spectrum V_O.

X3G_T_OH047_048

Product specification

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7. Bare die outline

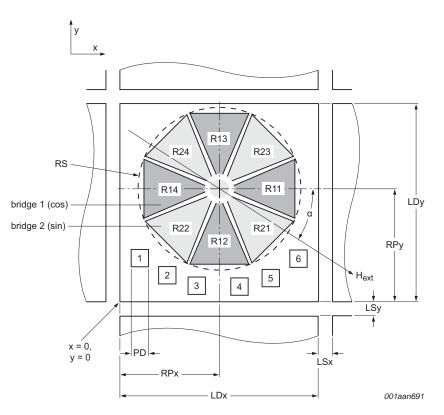


Fig 5. Bare die outline (single die)

| Table 7. | Mechanical dimensions for Figure 5 | | | | | |
|----------|------------------------------------|------|------|-----------------|------------|--|
| Symbol | Parameter | x | У | Radius/diameter | Unit | |
| LD | die size | 1150 | 1150 | - | μ m | |
| LS | sawing lane width | 60 | 60 | - | μ m | |
| RP | reading point position | 575 | 642 | - | μ m | |
| RS | sensitive area radius | - | - | 480 | μ m | |
| PD | pad diameter | - | - | 110 | μ m | |
| 1 | position pad 1 | 108 | 230 | - | μ m | |
| 2 | position pad 2 | 243 | 125 | - | μ m | |
| 3 | position pad 3 | 489 | 95 | - | μ m | |
| 4 | position pad 4 | 632 | 95 | - | μ m | |
| 5 | position pad 5 | 900 | 125 | - | μ m | |
| 6 | position pad 6 | 1032 | 200 | - | μm | |

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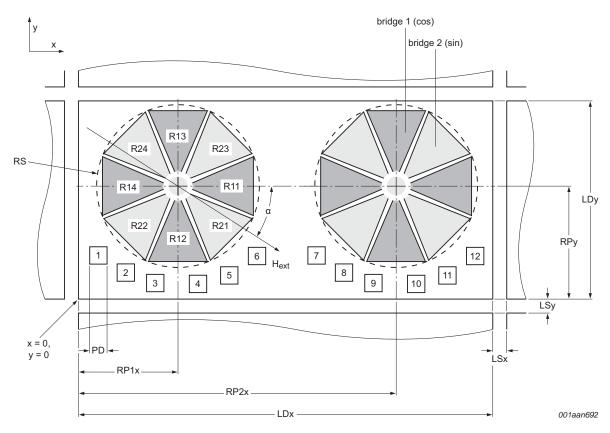


Fig 6. Bare die outline (double die)

Table 8. Mechanical dimensions for Figure 6

| Symbol | Parameter | x | У | Radius/diameter | Unit |
|--------|--------------------------|------|------|-----------------|------|
| LD | die size | 2360 | 1150 | | μm |
| LS | sawing lane width | 60 | 60 | | μm |
| RP1 | reading point position 1 | 575 | 642 | | μm |
| RP2 | reading point position 2 | 1785 | 642 | | μm |
| RS | sensitive area radius | - | - | 480 | μm |
| PD | pad diameter | - | - | 110 | μm |
| 1 | position pad 1 | 108 | 230 | | μm |
| 2 | position pad 2 | 243 | 125 | | μm |
| 3 | position pad 3 | 489 | 95 | | μm |
| 4 | position pad 4 | 632 | 95 | | μm |
| 5 | position pad 5 | 900 | 125 | | μm |
| 6 | position pad 6 | 1032 | 200 | | μm |
| 7 | position pad 7 | 1318 | 230 | | μm |
| 8 | position pad 8 | 1453 | 125 | | μm |
| 9 | position pad 9 | 1699 | 95 | | μm |

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X3G-OH047/8; X3T-OH047/8

150

 $\textbf{380} \pm \textbf{15}$

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mm

μm

| Symbol | Parameter | | 1 | /alue | Unit |
|----------|----------------------------------|-------------|-----|-----------------|------|
| Table 9. | Wafer dimensions | | | | |
| 12 | position pad 12 | 2242 | 200 | | μm |
| 11 | position pad 11 | 2110 | 125 | | μm |
| 10 | position pad 10 | 1842 | 95 | | μm |
| Symbol | Parameter | x | У | Radius/diameter | Unit |
| Table 8. | Mechanical dimensions for Figure | 6 continued | | | |

8. Packing information

wafer diameter

wafer thickness

WD

WT

8.1 Tape construction for X3G-OH047 and X3G-OH048

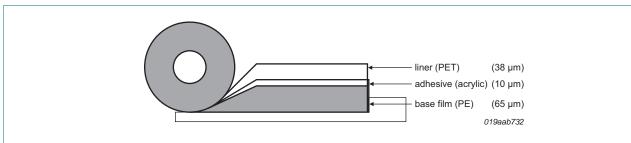


Fig 7. Tape construction

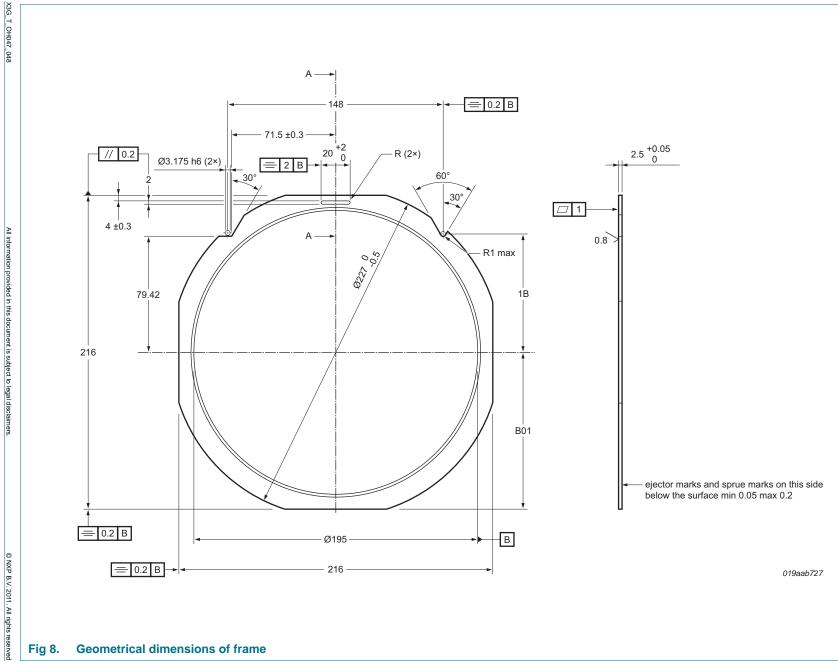
Table 10. Material composition

| Content | Typical value | Unit |
|---------|---|--|
| - | 75 | μm |
| - | 55 / 20 | g/mm |
| Na+ | 0.027 | μg/ml |
| K+ | < 0.004 | μg/ml |
| CI | 0.045 | μg/ml |
| | - - Na ⁺ K ⁺ | - 75 - 55 / 20 Na ⁺ 0.027 K ⁺ < 0.004 |

Product specification

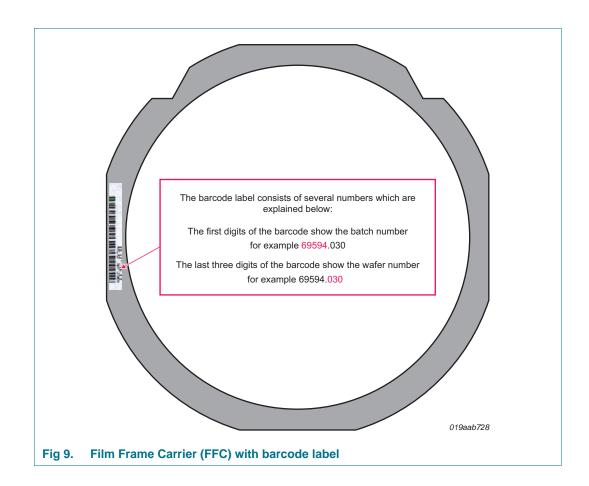


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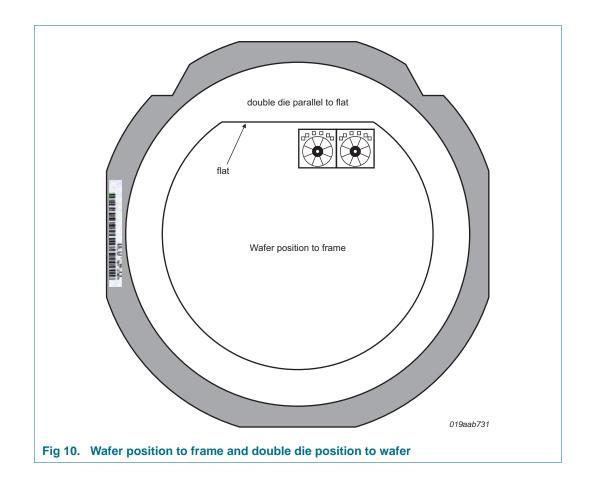


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8.2 Carrier tape for X3T-OH047 and X3T-OH048

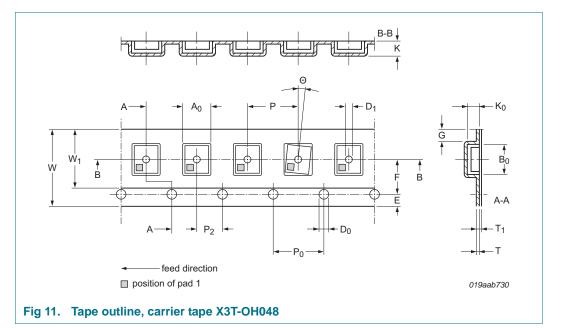


Table 11. Dimensions for Figure 11 "Tape outline, carrier tape X3T-OH048"

| Item | Symbol | Specification | | | |
|-------------------------------|--------------------------------------|-------------------------|------------------------------------|--|--|
| | | Dimension [mm] | Tolerance | | |
| Overall dimensions | | | | | |
| Tape width | W | 8 | ±0.1 | | |
| Thickness | К | ≤ 1.2 | - | | |
| Distance | G | ≥ 0.75 | - | | |
| Sprocket holes | | | | | |
| Diameter | D ₀ | 1.5 | ±0.1 | | |
| Distance | E | 1.75 | ±0.1 | | |
| Pitch ^[1] | P ₀ | 4 | ±0.1 | | |
| Distance between cente | er lines | | | | |
| Length direction | P ₂ | 2 | ±0.05 | | |
| Width direction | F | 3.5 | ±0.05 | | |
| Compartments | | | | | |
| Length | A ₀ | 1.4 | ±0.05 | | |
| Width | B ₀ | 1.4 | ±0.05 | | |
| Depth | K ₀ | 0.8 | ±0.05 | | |
| Hole diameter | D ₁ | 0.5 | ±0.1 | | |
| Pitch | Р | 4 | ±0.1 | | |
| Device | | | | | |
| Outline | X3T-OH048 | } | | | |
| Rotation | Θ | $\leq 20^{\circ}$ | - | | |
| Carrier tape antistatic | | | | | |
| Film thickness ^[2] | Т | 0.25 | ±0.07 | | |
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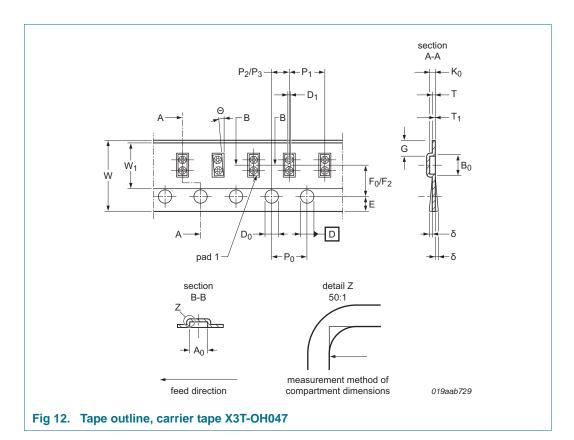
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 Table 11. Dimensions for Figure 11 "Tape outline, carrier tape X3T-OH048" ... continued

| Item | Symbol | Specification | | |
|----------------------|----------------|----------------|-----------|--|
| | | Dimension [mm] | Tolerance | |
| Cover tape | | | | |
| Width | W ₁ | ≤ 5.75 | - | |
| Film thickness | T ₁ | ≤ 0.1 | - | |
| Bending radius | | | | |
| In winding direction | R | ≥ 30 | - | |

[1] Cumulate pitch error ± 0.2 over 10 pitch.

[2] Carbon loaded polystyrene 100 % recyclable.



| Table 12 | Dimensions for | Figure 12 | 2 "Tane outline | carrier tane | X3T-OH047" |
|----------|-----------------------|-----------|-----------------|--------------|------------|
| | | FIGULE I | L Tabe outline. | carrier labe | A31-01047 |

| Item | Symbol | Specification | | |
|----------------------|----------------|----------------|-----------|--|
| | | Dimension [mm] | Tolerance | |
| Overall dimensions | | | | |
| Tape width | W | 8 | ±0.1 | |
| Distance | G | ≥ 0.75 | - | |
| Sprocket holes | | | | |
| Diameter | D ₀ | 1.5 | ±0.1 | |
| Distance | E | 1.75 | ±0.1 | |
| Pitch ^[1] | P ₀ | 4 | ±0.1 | |

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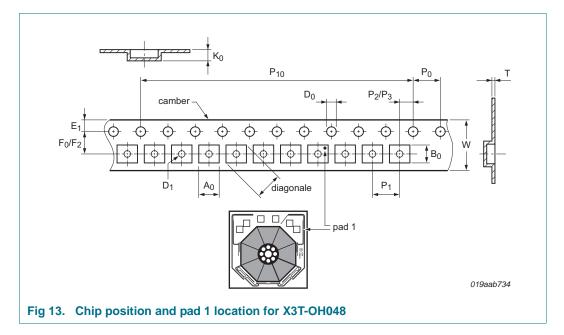
| Item | Symbol | Specification | Specification | | |
|-------------------------------|----------------|----------------|---------------|--|--|
| | | Dimension [mm] | Tolerance | | |
| Distance between center line | s | | ľ | | |
| Sprocket hole / cavity center | P ₂ | 2 | ±0.05 | | |
| Sprocket hole / cavity hole | P ₃ | 2 | ±0.05 | | |
| Sprocket hole / cavity center | F ₀ | 3.5 | ±0.05 | | |
| Sprocket hole / cavity hole | F_2 | 3.5 | ±0.05 | | |
| Compartments | | | | | |
| Length | A ₀ | 1.4 | ±0.05 | | |
| Width overall | B ₀ | 2.7 | ±0.05 | | |
| Depth | K ₀ | 0.5 | ±0.05 | | |
| Hole diameter | D ₁ | 0.5 | ±0.1 | | |
| Pitch | P ₁ | 4 | ±0.1 | | |
| Device | | | | | |
| Outline | X3T-OH047 | | | | |
| Rotation | Θ | ≤ 15 ° | - | | |
| Carrier tape antistatic | | | | | |
| Film thickness ^[2] | Т | 0.25 | ±0.07 | | |
| Bend | δ | ≤ 0.3 | - | | |
| Cover tape | | | | | |
| Width | W ₁ | 5.3 | ±0.1 | | |
| Film thickness | T ₁ | 0.05 | ±0.01 | | |
| Bending radius | | | | | |
| In winding direction | R | ≥ 30 | - | | |

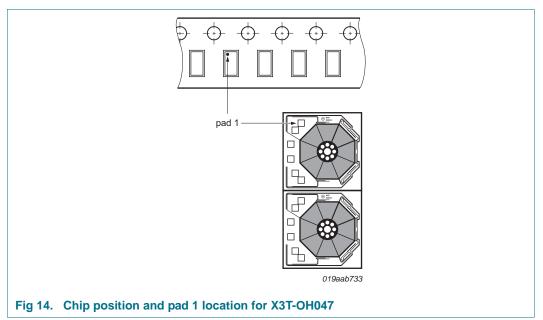
ensions for Figure 12 "Tape outline, carrier tape X3T-OH047" continued Dim

[1] Cumulate pitch error ± 0.2 over 10 pitch.

[2] Carbon loaded polystyrene 100 % recyclable.

Magnetic field sensor





9. Revision history

| Table 13. Revision history | | | | |
|------------------------------------|--------------|-----------------------|---------------|------------|
| Document ID | Release date | Data sheet status | Change notice | Supersedes |
| X3G_T_OH047_048 v.1 | 20110404 | Product specification | - | - |

X3G_T_OH047_048

10. Legal information

10.1 Data sheet status

| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
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[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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X3G_T_OH047_048

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